SC-74 Quad ESD and Surge Protector

Surge Protection Up to 350 W Peak Power

SMS05T1 Series

This quad monolithic silicon ESD and Surge Protector is designed for applications requiring ESD protection. It is intended for use in voltage and ESD sensitive equipment such as computers, printers, business machines, communication systems and other applications. This quad device provides superior surge protection over current quad Zener MMQA series by providing up to 350 watts peak power.

Features

- SC-74 Package Allows Four Separate Unidirectional Configurations
- Peak Power 350 W, 8 x 20 μs
- ESD Rating of Class N (Exceeding 25 kV) per the Human Body Model
- ESD Rating: IEC 61000-4-2 (ESD) 15 kV (Air) 8 kV (Contact) IEC 61000-4-4 (EFT) 40 A (5/5 ns) IEC 61000-4-5 (Surge) 23 A (8/20 μs)
- UL Flammability Rating of 94 V–0
- These Devices are Pb-Free and are RoHS Compliant
- SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable

Typical Applications

• Hand Held Portable Applications such as Cell Phones, Pagers, Notebooks and Notebook Computers

MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Peak Power Dissipation 8 x 20 μS @ T_A = 25°C (Note 1)	P _{pk}	350	W
Total Power Dissipation on FR-5 Board @ $T_A = 25^{\circ}C$ (Note 2)	PD	225	mW
Derate Above 25°C		1.8	mW/°C
Thermal Resistance, Junction-to-Ambient	$R_{\theta J A}$	556	°C/W
Junction and Storage Temperature Range	T _J , T _{stg}	-55 to +150	°C
Lead Solder Temperature Maximum 10 Seconds Duration	ΤL	260	°C

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. Non-repetitive current pulse 8 x 20 μs exponential decay waveform.

2. $FR-5 = 1.0 \times 0.75 \times 0.62$ in.



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SC-74 QUAD ESD AND SURGE PROTECTOR 350 WATTS PEAK POWER 5 VOLTS



SC-74 CASE 318F STYLE 1

MARKING DIAGRAM



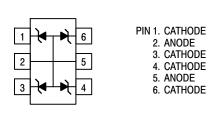
xxx = Specific Device Code

M = Date Code*

= Pb-Free Package

(Note: Microdot may be in either location) *Date Code orientation and/or position may vary depending upon manufacturing location.

PIN ASSIGNMENT



DEVICE MARKING INFORMATION

See specific marking information in the device marking column of the Electrical Characteristics table on page 2 of this data sheet.

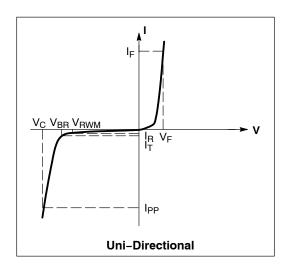
ORDERING INFORMATION

See detailed ordering, marking and shipping information in the ordering information section on page 2 of this data sheet.

ELECTRICAL CHARACTERISTICS

(T_A = 25°C unless otherwise noted)

Symbol	Parameter					
I _{PP}	Maximum Reverse Peak Pulse Current					
V _C	Clamping Voltage @ I _{PP}					
V _{RWM}	Working Peak Reverse Voltage					
I _R	Maximum Reverse Leakage Current @ V _{RWM}					
V _{BR}	Breakdown Voltage @ I _T					
Ι _Τ	Test Current					
ΘV_{BR}	Maximum Temperature Coefficient of V_{BR}					
١ _F	Forward Current					
V _F	Forward Voltage @ I _F					
Z _{ZT}	Maximum Zener Impedance @ I _{ZT}					
I _{ZK}	Reverse Current					
Z _{ZK}	Maximum Zener Impedance @ I _{ZK}					



ELECTRICAL CHARACTERISTICS - UNIDIRECTIONAL

	Breakdown Voltage		Breakdown Leak		Ma Reve Leak Curr	erse (Clamping age At Specifie		ng Voltage) (Clam fied Reverse At Spec		rse Voltage g Voltage) ed Reverse rrent (I _{RSM})	Capacitance @ 0 Volt Bias, 1 MHz		
	Device		V _{BR} (V)		Ι _Τ	I _R	V _R	l _{RSM} (8x20 μs)	V _{RSM} (8x20 μs)	l _{RSM} (8x20 μs)	V _{RSM} (8x20 μs)	(p	PF)
Device*	Marking	Min	Nom	Max	(mA)	(μΑ)	(V)	(A)	(V)	(A)	(V)	Min	Max
SMS05T1G	5V0	6.0	-	7.2	1.0	20	5.0	5.0	9.8	23	15.5	250	400
SMS12T1G	12V	13.3	-	15	1.0	1.0	12	5.0	19.0	15	23.0	80	150
SMS15T1G	15V	16.7	-	18.5	1.0	1.0	15	5.0	24.0	12	29.0	60	125
SMS24T1G	24V	26.7	-	32	1.0	1.0	24	5.0	40.0	8	44.0	40	75

*Includes SZ-prefix devices where applicable.

ORDERING INFORMATION

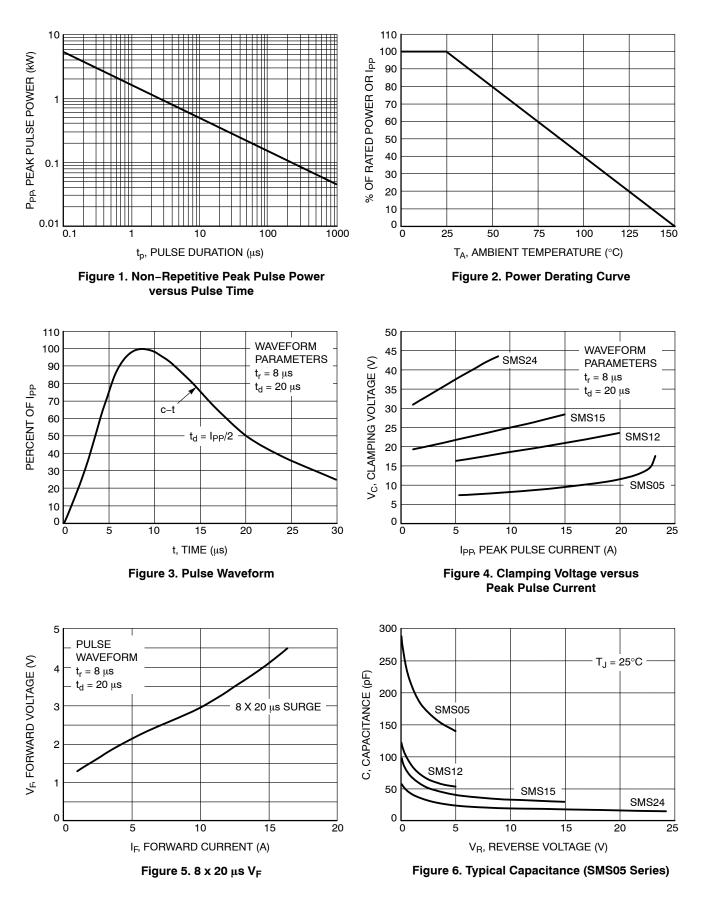
Device	Package	Shipping [†]
SMS05T1G, SZSMS05T1G**	SC-74 (Pb-Free)	3000 / Tape & Reel
SMS12T1G	SC-74 (Pb-Free)	3000 / Tape & Reel
SMS15T1G, SZSMS15T1G**	SC-74 (Pb-Free)	3000 / Tape & Reel
SMS24T1G, SZSMS24T1G**	SC-74 (Pb-Free)	3000 / Tape & Reel

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. **SZ Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP

Capable.

SMS05T1 Series

TYPICAL CHARACTERISTICS

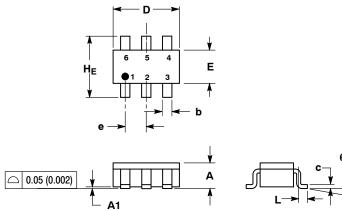


DATE 08 JUN 2012

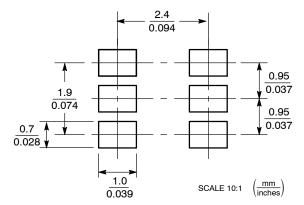




SCALE 2:1



SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

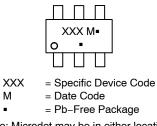
NOTES:

SC-74 CASE 318F-05 **ISSUE N**

- 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH
- CONTROLING DIMENSION: INCH. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH THICKNESS. MINIMUM LEAD THICKNESS IS THE MINIMUM З.
- THICKNESS OF BASE MATERIAL. 4. 318F-01, -02, -03, -04 OBSOLETE. NEW STANDARD 318F-05.

	М	ILLIMETE	RS	INCHES			
DIM	MIN	NOM	MAX	MIN	NOM	MAX	
Α	0.90	1.00	1.10	0.035	0.039	0.043	
A1	0.01	0.06	0.10	0.001	0.002	0.004	
b	0.25	0.37	0.50	0.010	0.015	0.020	
С	0.10	0.18	0.26	0.004	0.007	0.010	
D	2.90	3.00	3.10	0.114	0.118	0.122	
Е	1.30	1.50	1.70	0.051	0.059	0.067	
е	0.85	0.95	1.05	0.034	0.037	0.041	
L	0.20	0.40	0.60	0.008	0.016	0.024	
HE	2.50	2.75	3.00	0.099	0.108	0.118	
θ	0°	_	10°	0°	-	10°	

GENERIC **MARKING DIAGRAM***



(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " •", may or may not be present.

STYLE 1:	STYLE 2:	STYLE 3:	STYLE 4:	STYLE 5:	STYLE 6:
PIN 1. CATHODE	PIN 1. NO CONNECTION	PIN 1. EMITTER 1	PIN 1. COLLECTOR 2	PIN 1. CHANNEL 1	PIN 1. CATHODE
2. ANODE	2. COLLECTOR	2. BASE 1	2. EMITTER 1/EMITTER 2	2. ANODE	2. ANODE
3. CATHODE	3. EMITTER	3. COLLECTOR 2	3. COLLECTOR 1	3. CHANNEL 2	3. CATHODE
4. CATHODE	4. NO CONNECTION	4. EMITTER 2	4. EMITTER 3	4. CHANNEL 3	4. CATHODE
5. ANODE	5. COLLECTOR	5. BASE 2	5. BASE 1/BASE 2/COLLECTOR 3	5. CATHODE	5. CATHODE
6. CATHODE	6. BASE	6. COLLECTOR 1	6. BASE 3	6. CHANNEL 4	6. CATHODE
STYLE 7:	STYLE 8:	STYLE 9:	STYLE 10:	STYLE 11:	E
PIN 1. SOURCE 1	PIN 1. EMITTER 1	PIN 1. EMITTER 2	PIN 1. ANODE/CATHODE	PIN 1. EMITTER	
2. GATE 1	2. BASE 2	2. BASE 2	2. BASE	2. BASE	
3. DRAIN 2	3. COLLECTOR 2	3. COLLECTOR 1	3. EMITTER	3. ANODE/CATHODI	
4. SOURCE 2	4. EMITTER 2	4. EMITTER 1	4. COLLECTOR	4. ANODE	
5. GATE 2	5. BASE 1	5. BASE 1	5. ANODE	5. CATHODE	
6. DRAIN 1	6. COLLECTOR 1	6. COLLECTOR 2	6. CATHODE	6. COLLECTOR	

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DESCRIPTION:	DN: SC-74		PAGE 1 OF 1			

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PUBLICATION ORDERING INFORMATION

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TECHNICAL SUPPORT

ON Semiconductor Website: www.onsemi.com

Email Requests to: orderlit@onsemi.com

North American Technical Support: Voice Mail: 1 800–282–9855 Toll Free USA/Canada Phone: 011 421 33 790 2910 Europe, Middle East and Africa Technical Support: Phone: 00421 33 790 2910 For additional information, please contact your local Sales Representative